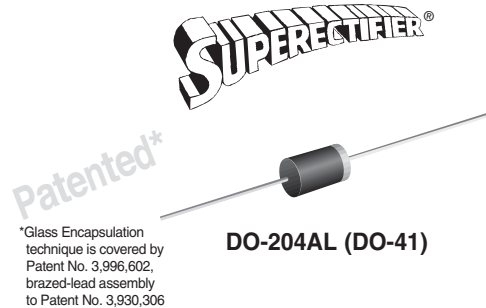




Glass Passivated Junction Fast Switching Rectifier

Major Ratings and Characteristics

$I_{F(AV)}$	1.0 A
V_{RRM}	50 V to 1000 V
I_{FSM}	30 A
t_{rr}	150 ns, 250 ns, 500 ns
I_R	5.0 μ A
V_F	1.3 V
T_j max.	175 °C



Features

- Superrectifier structure for High Reliability condition
- Cavity-free glass-passivated junction
- Fast switching for high efficiency
- Low leakage current
- High forward surge capability
- Meets environmental standard MIL-S-19500
- Solder Dip 260 °C, 40 seconds



Mechanical Data

Case: DO-204AL, molded epoxy over glass body
Epoxy meets UL-94V-0 Flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002B and JESD22-B102D
E3 suffix for commercial grade, HE3 suffix for high reliability grade (AEC Q101 qualified)

Polarity: Color band denotes cathode end

Typical Applications

For use in fast switching rectification of power supply, inverters, converters and freewheeling diodes for consumer, automotive and Telecommunication

Maximum Ratings

($T_A = 25\text{ °C}$ unless otherwise noted)

Parameter	Symbol	RGP10A	RGP10B	RGP10D	RGP10G	RGP10J	RGP10K	RGP10M	Unit
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum average forward rectified current 0.375" (9.5 mm) lead length at $T_A = 55\text{ °C}$	$I_{F(AV)}$	1.0							A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I_{FSM}	30							A
Maximum full load reverse current, full cycle average 0.375" (9.5 mm) lead length $T_A = 55\text{ °C}$	$I_{R(AV)}$	100							μ A
Operating junction and storage temperature range	T_J, T_{STG}	- 65 to + 175							°C

RGP10A thru RGP10M



Vishay General Semiconductor

Electrical Characteristics

($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)

Parameter	Test condition	Symbol	RGP10A	RGP10B	RGP10D	RGP10G	RGP10J	RGP10K	RGP10M	Unit
Maximum instantaneous forward voltage	at 1.0 A	V_F	1.3							V
Maximum DC reverse current at rated DC blocking voltage	$T_A = 25\text{ }^\circ\text{C}$ $T_A = 150\text{ }^\circ\text{C}$	I_R	5.0 200							μA
Maximum reverse recovery time	$I_F = 0.5\text{ A}$, $I_R = 1.0\text{ A}$, $t_{rr} = 0.25\text{ A}$	t_{rr}	150				250	500		ns
Typical junction capacitance	at 4.0 V, 1 MHz	C_J	15							pF

Thermal Characteristics

($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	RGP10A	RGP10B	RGP10D	RGP10G	RGP10J	RGP10K	RGP10M	Unit
Typical thermal resistance ⁽¹⁾	$R_{\theta JA}$	55							$^\circ\text{C/W}$

Notes:

(1) Thermal resistance from junction to ambient at 0.375" (9.5 mm) lead length, P.C.B. mounted

Ratings and Characteristics Curves

($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)

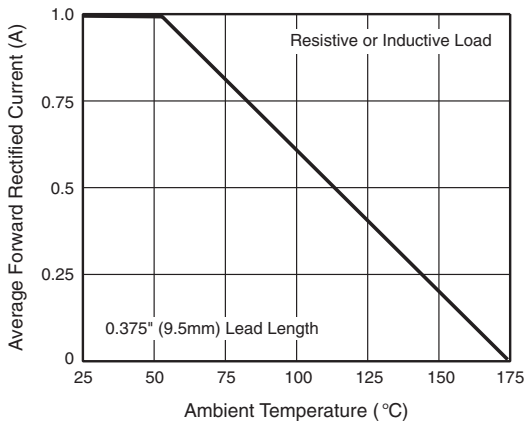


Figure 1. Forward Current Derating Curve

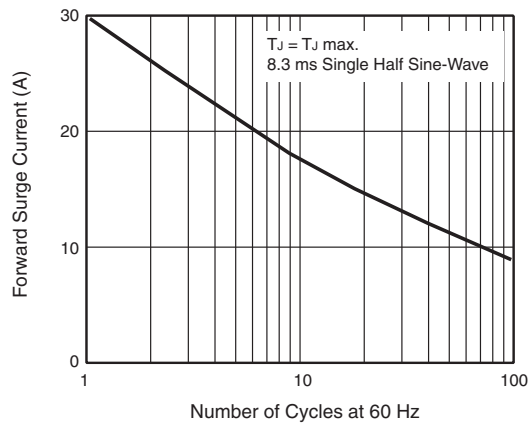


Figure 2. Maximum Non-repetitive Peak Forward Surge Current

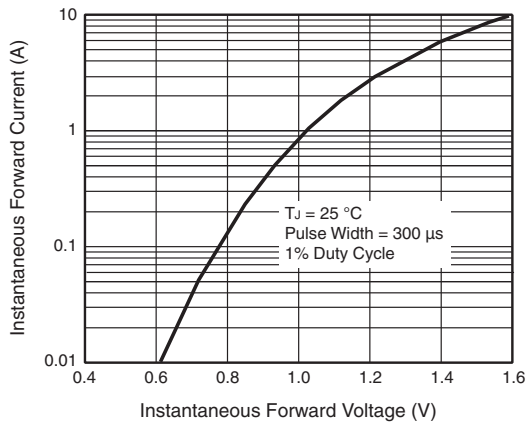


Figure 3. Typical Instantaneous Forward Characteristics

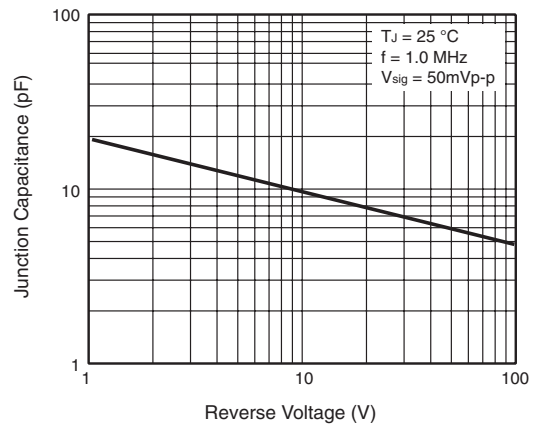


Figure 5. Typical Junction Capacitance

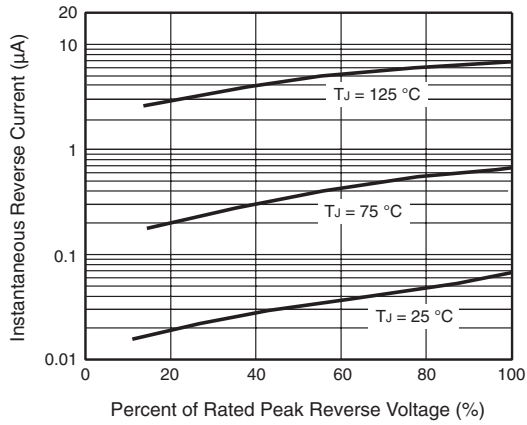


Figure 4. Typical Reverse Characteristics

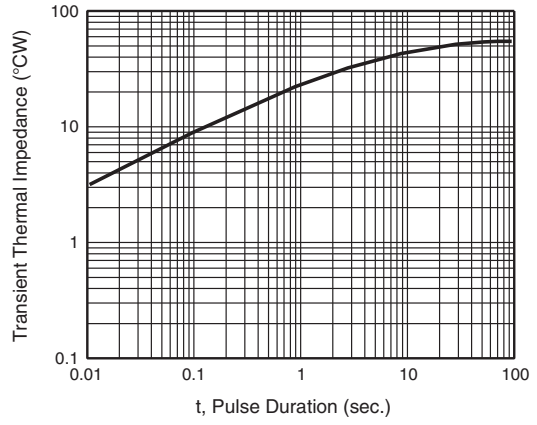


Figure 6. Typical Transient Thermal Impedance

Package outline dimensions in inches (millimeters)

